MC14066B

Quad Analog Switch/Quad Multiplexer

The MC14066B consists of four independent switches capable of controlling either digital or analog signals. This quad bilateral switch is useful in signal gating, chopper, modulator, demodulator and CMOS logic implementation.

The MC14066B is designed to be pin−for−pin compatible with the MC14016B, but has much lower ON resistance. Input voltage swings as large as the full supply voltage can be controlled via each independent control input.

- Triple Diode Protection on All Control Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Linearized Transfer Characteristics
- Low Noise — 12 nV/$\sqrt{\text{Cycle}}$, f ≥ 1.0 kHz typical
- Pin−for−Pin Replacement for CD4016, CD4016, MC14016B
- For Lower R_{ON}, Use The HC4066 High−Speed CMOS Device

MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 2.)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	−0.5 to +18.0	V
V_{in}, V_{out}	Input or Output Voltage Range (DC or Transient)	−0.5 to V_{DD} + 0.5	V
I_{in}	Input Current (DC or Transient) per Control Pin	±10	mA
I_{SW}	Switch Through Current	±25	mA
P_D	Power Dissipation, per Package (Note 3.)	500	mW
T_A	Ambient Temperature Range	−55 to +125	°C
T_{stg}	Storage Temperature Range	−65 to +150	°C
T_L	Lead Temperature (8−Second Soldering)	260	°C

2. Maximum Ratings are those values beyond which damage to the device may occur.
3. Temperature Derating:
   Plastic “P and D/DW” Packages: – 7.0 mW/°C From 65°C To 125°C

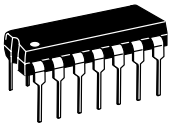
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high−impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \le (V_{in}$ or $V_{out}) \le V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

ON Semiconductor

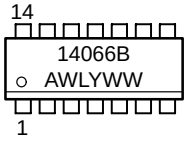
http://onsemi.com

MARKING DIAGRAMS

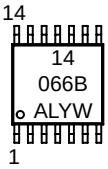


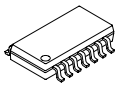
PDIP−14
P SUFFIX
CASE 646

SOIC−14
D SUFFIX
CASE 751A

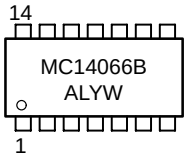


TSSOP−14
DT SUFFIX
CASE 948G





SOEIAJ−14
F SUFFIX
CASE 965



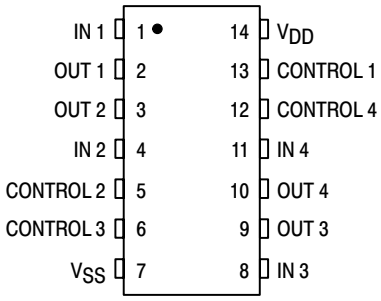
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week

ORDERING INFORMATION

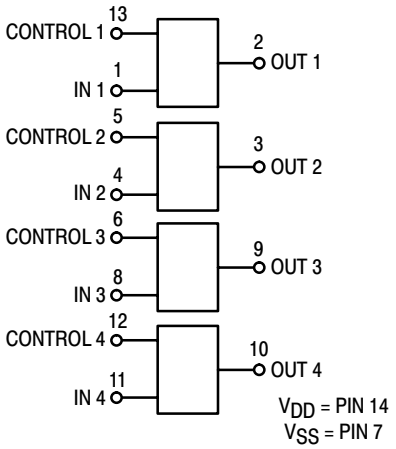
Device	Package	Shipping
MC14066BCP	PDIP−14	2000/Box
MC14066BD	SOIC−14	55/Rail
MC14066BDR2	SOIC−14	2500/Tape & Reel
MC14066BDT	TSSOP−14	96/Rail
MC14066BDTEL	TSSOP−14	2000/Tape & Reel
MC14066BDTR2	TSSOP−14	2500/Tape & Reel
MC14066BF	SOEIAJ−14	See Note 1.
MC14066BFEL	SOEIAJ−14	See Note 1.

1. For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

PIN ASSIGNMENT

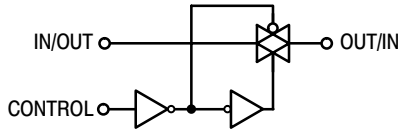


BLOCK DIAGRAM



LOGIC DIAGRAM AND TRUTH TABLE

(1/4 OF DEVICE SHOWN)



Control	Switch
0 = V_{SS}	OFF
1 = V_{DD}	ON

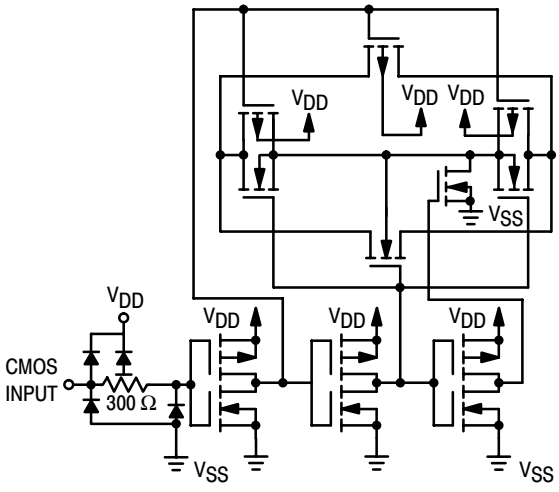
Logic Diagram Restrictions

$V_{SS} \le V_{in} \le V_{DD}$

$V_{SS} \le V_{out} \le V_{DD}$

CIRCUIT SCHEMATIC

(1/4 OF CIRCUIT SHOWN)



ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	V_{DD}	Test Conditions	− 55°C Min	− 55°C Max	25°C Min	25°C Typ (4.)	25°C Max	125°C Min	125°C Max	Unit
SUPPLY REQUIREMENTS (Voltages Referenced to V_{EE})											
Power Supply Voltage Range	V_{DD}	—		3.0	18	3.0	—	18	3.0	18	V
Quiescent Current Per Package	I_{DD}	5.0 10 15	Control Inputs: V_{in} = V_{SS} or V_{DD}, Switch I/O: $V_{SS} \le V_{I/O} \le V_{DD}$, and $\Delta V_{switch} \le 500$ mV (5.)	— — —	0.25 0.5 1.0	— — —	0.005 0.010 0.015	0.25 0.5 1.0	— — —	7.5 15 30	μA
Total Supply Current (Dynamic Plus Quiescent, Per Package	$I_{D(AV)}$	5.0 10 15	T_A = 25°C only The channel component, $(V_{in} - V_{out})/R_{on}$, is not included.)	Typical			(0.07 μA/kHz) f + I_{DD} (0.20 μA/kHz) f + I_{DD} (0.36 μA/kHz) f + I_{DD}				μA
CONTROL INPUTS (Voltages Referenced to V_{SS})											
Low−Level Input Voltage	V_{IL}	5.0 10 15	R_{on} = per spec, I_{off} = per spec	— — —	1.5 3.0 4.0	— — —	2.25 4.50 6.75	1.5 3.0 4.0	— — —	1.5 3.0 4.0	V
High−Level Input Voltage	V_{IH}	5.0 10 15	R_{on} = per spec, I_{off} = per spec	3.5 7.0 11	— — —	3.5 7.0 11	2.75 5.50 8.25	— — —	3.5 7.0 11	— — —	V
Input Leakage Current	I_{in}	15	V_{in} = 0 or V_{DD}	—	± 0.1	—	±0.00001	± 0.1	—	± 1.0	μA
Input Capacitance	C_{in}	—		—	—	—	5.0	7.5	—	—	pF
SWITCHES IN AND OUT (Voltages Referenced to V_{SS})											
Recommended Peak−to−Peak Voltage Into or Out of the Switch	$V_{I/O}$	—	Channel On or Off	0	V_{DD}	0	—	V_{DD}	0	V_{DD}	V_{p-p}
Recommended Static or Dynamic Voltage Across the Switch (5.) (Figure 1)	ΔV_{switch}	—	Channel On	0	600	0	—	600	0	300	mV
Output Offset Voltage	V_{OO}	—	V_{in} = 0 V, No Load	—	—	—	10	—	—	—	μV
ON Resistance	R_{on}	5.0 10 15	$\Delta V_{switch} \le 500$ mV (5.), V_{in} = V_{IL} or V_{IH} (Control), and V_{in} = 0 to V_{DD} (Switch)	— — —	800 400 220	— — —	250 120 80	1050 500 280	— — —	1200 520 300	Ω
ΔON Resistance Between Any Two Channels in the Same Package	ΔR_{on}	5.0 10 15		— — —	70 50 45	— — —	25 10 10	70 50 45	— — —	135 95 65	Ω
Off−Channel Leakage Current (Figure 6)	I_{off}	15	V_{in} = V_{IL} or V_{IH} (Control) Channel to Channel or Any One Channel	—	±100	—	± 0.05	±100	—	±1000	nA
Capacitance, Switch I/O	$C_{I/O}$	—	Switch Off	—	—	—	10	15	—	—	pF
Capacitance, Feedthrough (Switch Off)	$C_{I/O}$	— —		—	—	—	0.47	—	—	—	pF

4. Data labeled “Typ” is not to be used for design purposes, but is intended as an indication of the IC’s potential performance.
5. For voltage drops across the switch (ΔV_{switch}) > 600 mV (> 300 mV at high temperature), excessive V_{DD} current may be drawn; i.e. the current out of the switch may contain both V_{DD} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

ELECTRICAL CHARACTERISTICS [6.] (C_L = 50 pF, T_A = 25°C unless otherwise noted.)

Characteristic	Symbol	V_{DD} Vdc	Min	Typ [7.]	Max	Unit
Propagation Delay Times V_{SS} = 0 Vdc	t_{PLH}, t_{PHL}					ns
Input to Output (R_L = 10 kΩ)						
t_{PLH}, t_{PHL} = (0.17 ns/pF) C_L + 15.5 ns		5.0	—	20	40	
t_{PLH}, t_{PHL} = (0.08 ns/pF) C_L + 6.0 ns		10	—	10	20	
t_{PLH}, t_{PHL} = (0.06 ns/pF) C_L + 4.0 ns		15	—	7.0	15	
Control to Output (R_L = 1 kΩ) (Figure 2)	t_{PHZ}					ns
Output “1” to High Impedance		5.0	—	40	80	
		10	—	35	70	
		15	—	30	60	
Output “0” to High Impedance	t_{PLZ}	5.0	—	40	80	ns
		10	—	35	70	
		15	—	30	60	
High Impedance to Output “1”	t_{PZH}	5.0	—	60	120	ns
		10	—	20	40	
		15	—	15	30	
High Impedance to Output “0”	t_{PZL}	5.0	—	60	120	ns
		10	—	20	40	
		15	—	15	30	
Second Harmonic Distortion V_{SS} = – 5 Vdc (V_{in} = 1.77 Vdc, RMS Centered @ 0.0 Vdc, R_L = 10 kΩ, f = 1.0 kHz)	—	5.0	—	0.1	—	%
Bandwidth (Switch ON) (Figure 3) V_{SS} = – 5 Vdc (R_L = 1 kΩ, 20 Log (V_{out}/V_{in}) = − 3 dB, C_L = 50 pF, V_{in} = 5 V_{p-p})	—	5.0	—	65	—	MHz
Feedthrough Attenuation (Switch OFF) V_{SS} = – 5 Vdc (V_{in} = 5 V_{p-p}, R_L = 1 kΩ, f_{in} = 1.0 MHz) (Figure 3)	—	5.0	—	– 50	—	dB
Channel Separation (Figure 4) V_{SS} = – 5 Vdc (V_{in} = 5 V_{p-p}, R_L = 1 kΩ, f_{in} = 8.0 MHz) (Switch A ON, Switch B OFF)	—	5.0	—	– 50	—	dB
Crosstalk, Control Input to Signal Output (Figure 5) V_{SS} = – 5 Vdc (R_1 = 1 kΩ, R_L = 10 kΩ, Control t_{TLH} = t_{THL} = 20 ns)	—	5.0	—	300	—	mV_{p-p}

6. The formulas given are for the typical characteristics only at 25°C.
7. Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

TEST CIRCUITS

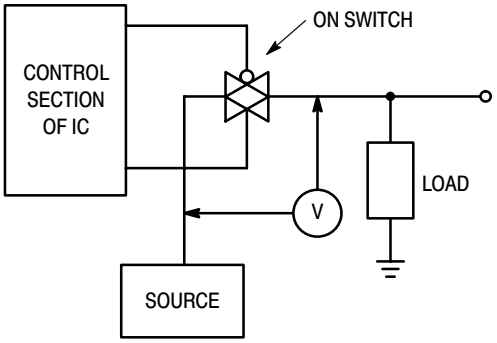


Figure 1. ΔV Across Switch

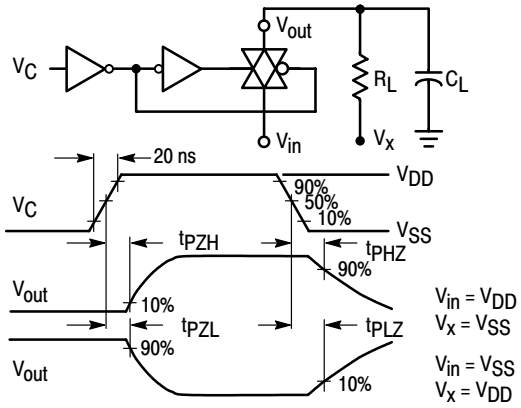


Figure 2. Turn−On Delay Time Test Circuit and Waveforms

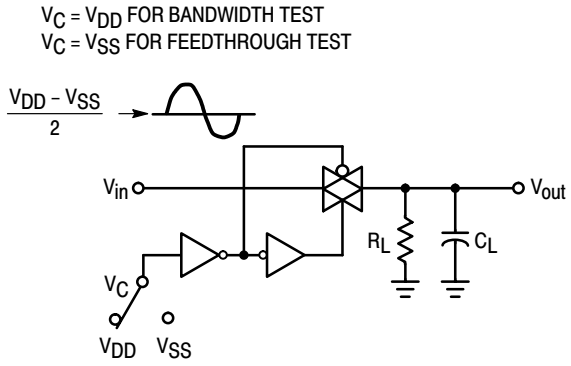


Figure 3. Bandwidth and Feedthrough Attenuation

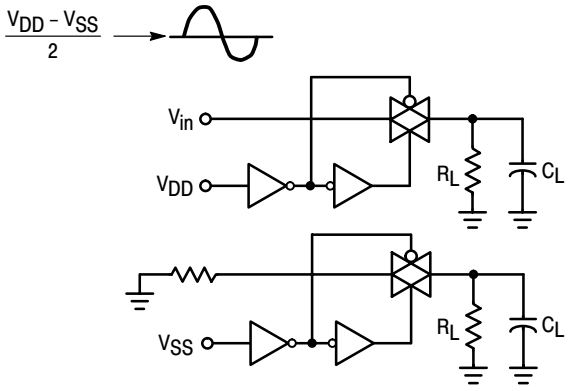


Figure 4. Channel Separation

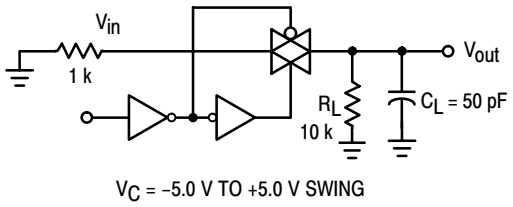


Figure 5. Crosstalk, Control to Output

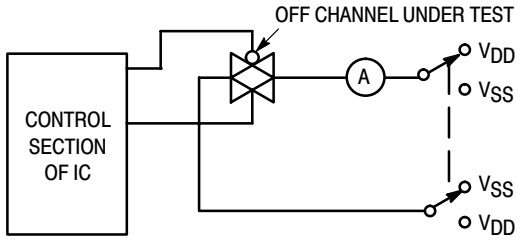


Figure 6. Off Channel Leakage

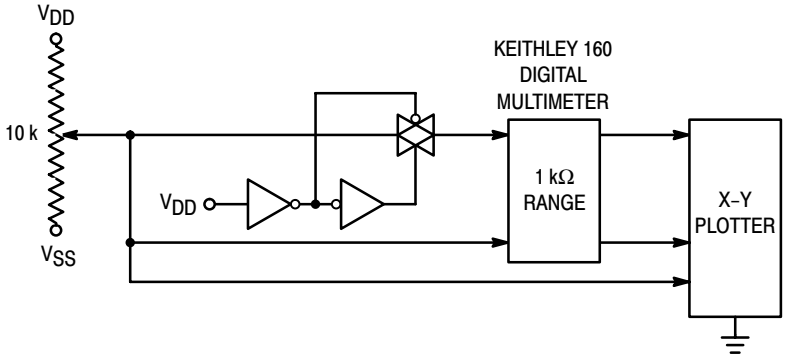


Figure 7. Channel Resistance (R_{ON}) Test Circuit

TYPICAL RESISTANCE CHARACTERISTICS

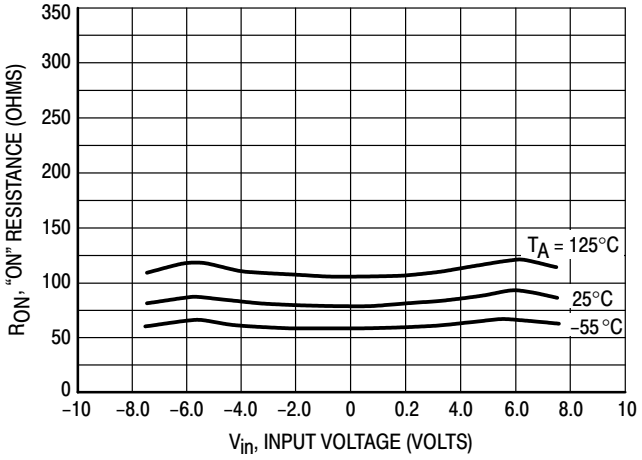


Figure 8. V_{DD} = 7.5 V, V_{SS} = − 7.5 V

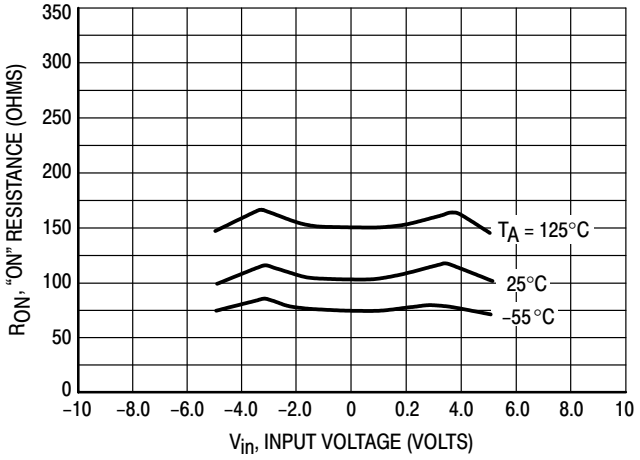


Figure 9. V_{DD} = 5.0 V, V_{SS} = − 5.0 V

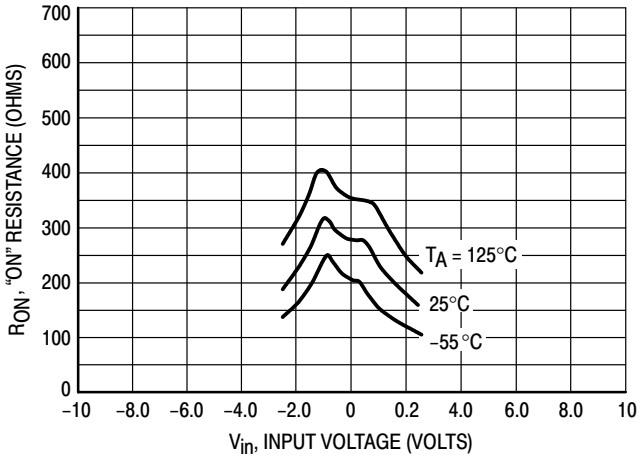


Figure 10. V_{DD} = 2.5 V, V_{SS} = − 2.5 V

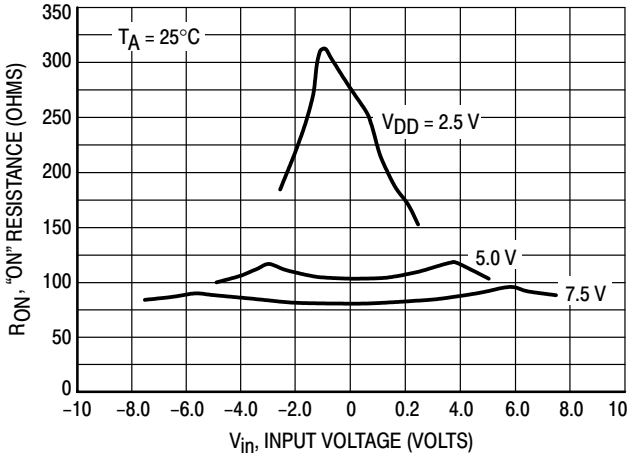


Figure 11. Comparison at 25°C, V_{DD} = −V_{SS}

APPLICATIONS INFORMATION

Figure A illustrates use of the Analog Switch. The 0−to−5 volt digital control signal is used to directly control a 5 volt peak−to−peak analog signal.

The digital control logic levels are determined by V_{DD} and V_{SS}. The V_{DD} voltage is the logic high voltage, the V_{SS} voltage is logic low. For the example, V_{DD} = + 5 V = logic high at the control inputs; V_{SS} = GND = 0 V = logic low.

The maximum analog signal level is determined by V_{DD} and V_{SS}. The analog voltage must not swing higher than V_{DD} or lower than V_{SS}.

The example shows a 5 volt peak−to−peak signal which allows no margin at either peak. If voltage transients above V_{DD} and/or below V_{SS} are anticipated on the analog channels, external diodes (D_X) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The *absolute* maximum potential difference between V_{DD} and V_{SS} is 18.0 volts. Most parameters are specified up to 15 volts which is the *recommended* maximum difference between V_{DD} and V_{SS}.

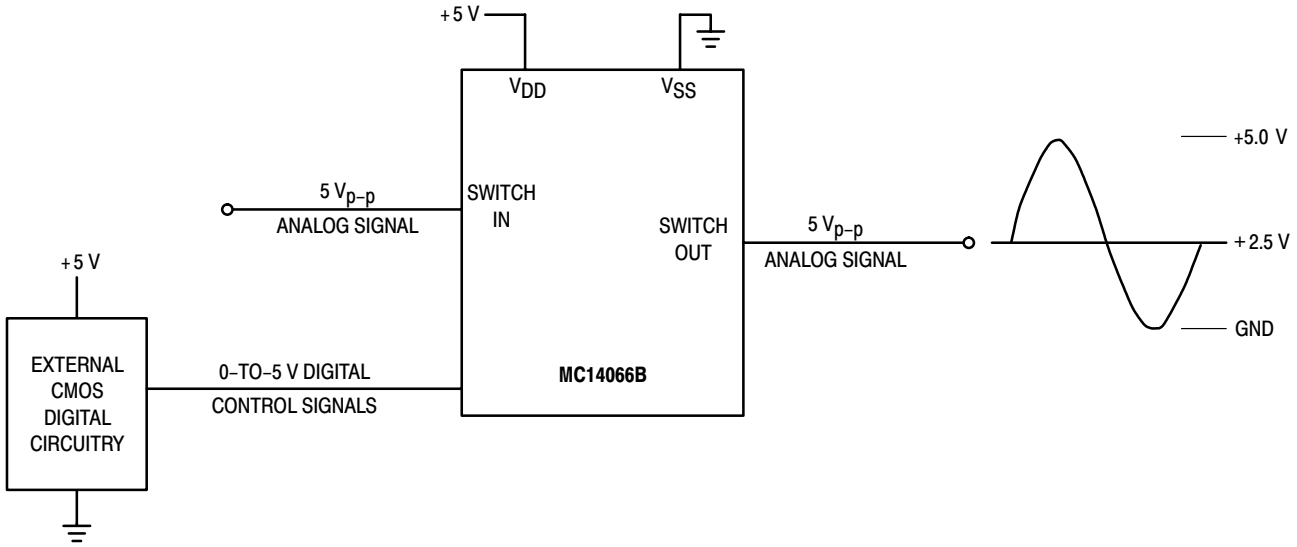


Figure A. Application Example

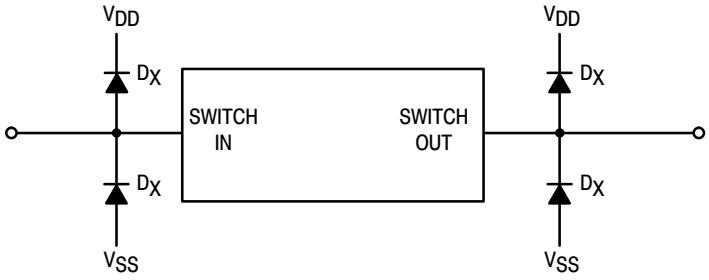


Figure B. External Germanium or Schottky Clipping Diodes